MAAP-011218-DIE

0.5 W Power Amplifier
71 - 86 GHz

Features
- 4 Stage Power Amplifier for E-Band
- 20 dB Gain
- 8 dB Input and Output Match
- 27 dBm Saturated Output Power
- 31 dBm OIP3
- Variable Gain with Adjustable Bias
- Integrated Detector
- 2790 x 1950 x 50 μm Bare Die
- RoHS* Compliant

Description
The MAAP-011218 is a bare die power amplifier that operates from 71 - 86 GHz. The amplifier provides 20 dB small signal gain, 27 dBm output power and 31 dBm Output Third Order Intercept Point (OIP3). An integrated temperature compensated power detector is on-chip. The input and output are matched to 50 Ω with bond wires to external board.

This amplifier is designed for use as a power amplifier stage in transmit chains and is ideally suited for E-band point-to-point radios. Each device is 100% RF tested to ensure performance compliance.

Ordering Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>MAAP-011218-DIE</td>
<td>Vacuum Release Gel Pak¹</td>
</tr>
</tbody>
</table>

1. Die quantity varies.

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

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### Electrical Specifications: $I_{DQ} = 760\,\text{mA (Full Bias)}, V_D = 4\,\text{V}, Z_0 = 50\,\Omega, T_A = 25^\circ\text{C}$

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Gain</strong></td>
<td>71 - 76 GHz</td>
<td>dB</td>
<td>17</td>
<td>15</td>
<td>15</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>15</td>
<td>15</td>
<td>17</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>15</td>
<td>15</td>
<td>17</td>
</tr>
<tr>
<td><strong>Input Return Loss</strong></td>
<td>71 - 76 GHz</td>
<td>dB</td>
<td>—</td>
<td>8</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>10</td>
<td>10</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>5</td>
<td>5</td>
<td>5</td>
</tr>
<tr>
<td><strong>Output Return Loss</strong></td>
<td>71 - 76 GHz</td>
<td>dB</td>
<td>—</td>
<td>7</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>10</td>
<td>10</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>7</td>
<td>7</td>
<td>7</td>
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<tr>
<td><strong>Noise Figure</strong></td>
<td>71 - 76 GHz</td>
<td>dB</td>
<td>—</td>
<td>7</td>
<td>7</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>7</td>
<td>7</td>
<td>7</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>7</td>
<td>7</td>
<td>7</td>
</tr>
<tr>
<td><strong>OIP3</strong></td>
<td>$P_{IN} = -5,\text{dBm/tone, 11 MHz Tone Spacing}$</td>
<td>dBm</td>
<td>—</td>
<td>32</td>
<td>31</td>
</tr>
<tr>
<td></td>
<td>71 - 76 GHz</td>
<td></td>
<td>31</td>
<td>31</td>
<td>31</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>31</td>
<td>31</td>
<td>31</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>—</td>
<td>31</td>
<td>31</td>
</tr>
<tr>
<td><strong>Output P1dB</strong></td>
<td>71 - 76 GHz</td>
<td>dBm</td>
<td>—</td>
<td>26</td>
<td>25</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>25</td>
<td>25</td>
<td>25</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>—</td>
<td>25</td>
<td>25</td>
</tr>
<tr>
<td><strong>$P_{SAT}$</strong></td>
<td>71 - 76 GHz</td>
<td>dBm</td>
<td>25</td>
<td>25</td>
<td>25</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>25</td>
<td>25</td>
<td>25</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>25</td>
<td>25</td>
<td>25</td>
</tr>
<tr>
<td><strong>Efficiency</strong></td>
<td>$\text{@ P1dB}$</td>
<td>%</td>
<td>—</td>
<td>12</td>
<td>6</td>
</tr>
<tr>
<td></td>
<td>71 - 76 GHz</td>
<td></td>
<td>6</td>
<td>6</td>
<td>6</td>
</tr>
<tr>
<td></td>
<td>76 - 81 GHz</td>
<td></td>
<td>—</td>
<td>15</td>
<td>9</td>
</tr>
<tr>
<td></td>
<td>81 - 86 GHz</td>
<td></td>
<td>9</td>
<td>9</td>
<td>9</td>
</tr>
</tbody>
</table>
Electrical Specifications: $I_{DQ} = 460 \text{ mA (Reduced Bias)}, V_D = 4 \text{ V}, Z_0 = 50 \Omega, T_A = 25^\circ \text{C}$

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
</table>
| Gain                 | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dB    | 17   | 14   | —    |
| Input Return Loss    | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dB    | 8    | 10   | 5    |
| Output Return Loss   | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dB    | 6    | 8    | —    |
| Noise Figure         | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dB    | 7    | 7    | —    |
| OIP3                 | $P_{IN} = -5 \text{ dBm/tone, 11 MHz Tone Spacing}$  
71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dBm   | 29   | 29   | —    |
| Output P1dB          | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dBm   | 26   | 24   | —    |
| $P_{SAT}$            | 71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | dBm   | 27   | 25   | —    |
| Efficiency           | $@ \text{ P1dB}$  
71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | %     | 9    | 6    | 6    |
|                      | $@ \text{ P}_{SAT}$  
71 - 76 GHz  
76 - 81 GHz  
81 - 86 GHz          | %     | 15   | 9    | 9    |
Recommended Quiescent Bias Currents, All Drain Supply Voltages are +4 V

<table>
<thead>
<tr>
<th>Bias</th>
<th>I₀1 mA</th>
<th>I₀2 mA</th>
<th>I₀3 mA</th>
<th>I₀4 mA</th>
<th>Total mA</th>
</tr>
</thead>
<tbody>
<tr>
<td>Full Bias</td>
<td>120</td>
<td>120</td>
<td>200</td>
<td>320</td>
<td>760</td>
</tr>
<tr>
<td>Reduced Bias</td>
<td>70</td>
<td>70</td>
<td>120</td>
<td>200</td>
<td>460</td>
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</table>

Absolute Maximum Ratings$^{4,5}$

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Drain Voltage</td>
<td>+4.3 V</td>
</tr>
<tr>
<td>Gate Bias Voltage</td>
<td>-1.5 V &lt; V_G &lt; +0.3 V</td>
</tr>
<tr>
<td>Drain Current</td>
<td>1135 mA</td>
</tr>
<tr>
<td>Input Power</td>
<td>20 dBm</td>
</tr>
<tr>
<td>Junction Temperature$^{6,7}$</td>
<td>+150°C</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40°C to +85°C</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-55°C to +150°C</td>
</tr>
</tbody>
</table>

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These Class 1B electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

4. Exceeding any one or combination of these limits may cause permanent damage to this device.
5. MACOM does not recommend sustained operation near these survivability limits.
6. Operating at nominal conditions with T_J ≤ +150°C will ensure MTTF > 1 x 10⁹ hours.
7. Typical thermal resistance ($\Theta_{JC}$) = 10.95°C/W.
Junction Temperature ($T_J$) = Back Plate Temperature ($T_{BP}$) + $\Theta_{JC}$ * (V*I).
   a) For $T_{BP}$ = +25°C,
      $T_J$ = 58°C @ 4 V, 760 mA
   b) For $T_{BP}$ = +85°C,
      $T_J$ = 118°C @ 4 V, 760 mA
Layout Dimensions \(^8,9\)

8. All units in the outline drawing are microns, with a tolerance of \(\pm 5 \, \mu m\), except for die exterior dimensions which are street-centre-to-centre minus the nominal kerf, \(\pm 20 \, \mu m\) tolerance.

9. Die Thickness is \(50 \pm 10 \, \mu m\).

<table>
<thead>
<tr>
<th>Pad</th>
<th>Size (x) (\mu m)</th>
<th>Size (y) (\mu m)</th>
</tr>
</thead>
<tbody>
<tr>
<td>B, L</td>
<td>65</td>
<td>157</td>
</tr>
<tr>
<td>D, E, F, G, I, J, O, P, Q</td>
<td>100</td>
<td>100</td>
</tr>
<tr>
<td>H, N</td>
<td>250</td>
<td>100</td>
</tr>
<tr>
<td>A, C, K, M</td>
<td>100</td>
<td>80</td>
</tr>
</tbody>
</table>

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Typical Performance Curves: \( I_{DG} = 760 \, \text{mA}, \, V_D = 4 \, \text{V}, \, \text{Full Bias} \)

- **S11**
- **S12**
- **S21**
- **S22**
Typical Performance Curves: $I_{DQ} = 760$ mA, $V_D = 4$ V, Full Bias

**S21 (Wideband)**

-80 to 30 dB

**S12 (Wideband)**

-80 to 0 dB

-40°C, +25°C, +85°C

**S11 (Wideband)**

-30 to 0 dB

**S22 (Wideband)**

-30 to 0 dB

-40°C, +25°C, +85°C
0.5 W Power Amplifier
71 - 86 GHz

Typical Performance Curves: $I_{DQ} = 460$ mA, $V_D = 4$ V, Reduced Bias

**S21**

**S11**

**S12**

**S22**

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Typical Performance Curves: $V_D = 4$ V

$S21$ at Room Temperature vs. Total Drain Current*

$S21$ at Hot Temperature vs. Total Drain Current*

$S21$ at Cold Temperature vs. Total Drain Current*

*Total Drain currents were set at 80, 150, 230, 300, 380, 460, 530, 610, 680, 760, 840, 910, and 980 mA.
Typical Performance Curves: \(I_{\text{DQ}} = 760\) mA, \(V_D = 4\) V (Full Bias)

**Saturated Power and PAE**

- **Output P1dB**

- **Gain and PAE vs. \(P_{\text{OUT}}\) @ 71 GHz**

- **Gain and PAE vs. \(P_{\text{OUT}}\) @ 76 GHz**

- **Gain and PAE vs. \(P_{\text{OUT}}\) @ 81 GHz**

- **Gain and PAE vs. \(P_{\text{OUT}}\) @ 86 GHz**
Typical Performance Curves: I_DQ = 460 mA, V_D = 4 V (Reduced Bias)

Saturated Power and PAE

Output P1dB

Gain and PAE vs. P_OUT @ 71 GHz

Gain and PAE vs. P_OUT @ 81 GHz

Gain and PAE vs. P_OUT @ 76 GHz

Gain and PAE vs. P_OUT @ 86 GHz

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Typical Performance Curves: $I_{DQ} = 760 \ mA$, $V_D = 4 \ V$, Full Bias, RF $P_{IN} = -5 \ dBm/tone$

Typical Performance Curves: $I_{DQ} = 460 \ mA$, $V_D = 4 \ V$, Reduced Bias, RF $P_{IN} = -5 \ dBm/tone$
Typical Performance Curves: $I_{DQ} = 760 \text{ mA}, V_D = 4 \text{ V}, \text{ Full Bias}$

**Detector Delta Voltage vs. Output Power, 71 - 76 GHz**

**Detector Delta Voltage vs. Output Power, 81 - 86 GHz**

**Noise Figure @ Full and Reduced Bias**
Calibration Plane -
All data was measured on die with 200 µm pitch probes. All data was measured with an ISS cal.

App Note [1] Biasing -
All gates should be pinched-off ($V_G < -1$ V) before applying drain voltage ($V_D = 4$ V). Then the gate voltages can be increased until the desired quiescent drain current is reached in each stage. The recommended quiescent full bias is $V_D = 4$ V, $I_{D1} = 120$ mA, $I_{D2} = 120$ mA, $I_{D3} = 200$ mA and $I_{D4} = 320$ mA. The performance in this datasheet has been measured with fixed gate voltage and no drain current regulation under large signal operation. It is also possible to regulate the drain current dynamically, to limit the DC power dissipation under RF drive. To turn off the device, the turn on bias sequence should be followed in reverse.

App Note [2] Bias Arrangement -
Each DC pin ($V_{D1,2,3,4}$ and $V_{G1,2,3,4}$) needs to have bypass capacitors (120 pF and 10 nF) mounted as close to the MMIC as possible.

App Note [3] Common Gates and Drains -
When biasing the device with only a single gate or drain source additional isolation is required between each stage. On the gate side a 10 Ω resistor should be placed in series and tied together in a star to a common supply. The drain side resistance should be reduced to less than 5 Ω to minimize any voltage drop across the resistor. Suitable bypass capacitors should still accompany each stage as per App Note [2].

App Note [4] Detector Biasing Schematic -
As shown in the schematic below, the power detector is biased by matched 100 kΩ resistors to a +5 V supply. The difference voltage between $V_{DET}$ and $V_{REF}$ pins can be obtained using a differencing circuit.

App Note [5] Wire Bonding -
The loop height of the RF bonds should be minimized. Where the die is mounted above the PCB, it is recommended to use Reverse Ball-Stitch-on-Ball bonds (BSOB). If the die is mounted inside a cavity on the board, forward loop bonding may result in a lower loop height. V-shape RF bond with two wires (diameter = 20 µm) is recommended for optimum RF performance. RF bond wire length to be minimized to reduce the inductance effect. Simulations suggest no more than 300 µm. Substrate RF pad can be optimized to improve the microstrip to MMIC bond transition as shown in the example below. Please see App Note [6] for further details.
App Note [6] RF Matching -
MAAP-011218 is designed to be a wideband RF power amplifier covering the 71 - 86 GHz band. By covering the full band, it enables customers to simplify BOM and circuitry for simple wideband performance. In cases where narrower band performance is preferred, external matching can be used to further optimise the return loss of the MMIC.

The board material used for matching was Isola Astra MT77. This has a dielectric constant ($\varepsilon_r$) = 3 and a loss tangent (tan $\delta$) of 0.0015. Simulations of the transition were performed in Analyst and can be provided on request. Transitions have been simulated to maintain return loss of -8 dB across the two bands of interest using Analyst.

Low Band Gain

High Band Gain

Low Band Return Loss

High Band Return Loss

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Input Dimensions
Common to every optimisation

Low Band Optimisation
Input Side

Low Band Optimisation
Output Side
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